

# 74CBTLV3126-Q100

## 4-bit bus switch

Rev. 3 — 9 October 2018

Product data sheet

## 1. General description

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The 74CBTLV3126-Q100 provides a 4-bit high-speed bus switch with separate output enable inputs (1OE to 4OE). The low on-state resistance of the switch allows connections to be made with minimal propagation delay. The switch is disabled (high-impedance OFF-state) when the output enable (nOE) input is LOW.

To ensure the high-impedance OFF-state during power-up or power-down, nOE should be tied to the GND through a pull-down resistor. The current-sinking capability of the driver determines the minimum value of the resistor.

Schmitt trigger action at control input makes the circuit tolerant to slower input rise and fall times across the entire  $V_{CC}$  range from 2.3 V to 3.6 V.

This device is fully specified for partial power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

## 2. Features and benefits

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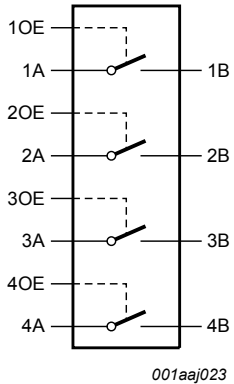
- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Supply voltage range from 2.3 V to 3.6 V
- Standard '126'-type pinout
- High noise immunity
- Complies with JEDEC standard:
  - JESD8-5 (2.3 V to 2.7 V)
  - JESD8-B/JESD36 (2.7 V to 3.6 V)
- ESD protection:
  - MIL-STD-883, method 3015 exceeds 2000 V
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- 5 Ω switch connection between two ports
- Rail to rail switching on data I/O ports
- CMOS low power consumption
- Latch-up performance exceeds 250 mA per JESD78B Class I level A
- $I_{OFF}$  circuitry provides partial Power-down mode operation

### 3. Ordering information

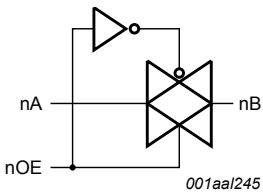
Table 1. Ordering information

| Type number        | Package           |          |  | Version  |
|--------------------|-------------------|----------|--|----------|
|                    | Temperature range | Name     | Description  |          |
| 74CBTLV3126PW-Q100 | -40 °C to +125 °C | TSSOP14  | plastic thin shrink small outline package; 14 leads; body width 4.4 mm   | SOT402-1 |
| 74CBTLV3126BQ-Q100 | -40 °C to +125 °C | DHVQFN14 | plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 × 3 × 0.85 mm | SOT762-1 |

### 4. Functional diagram



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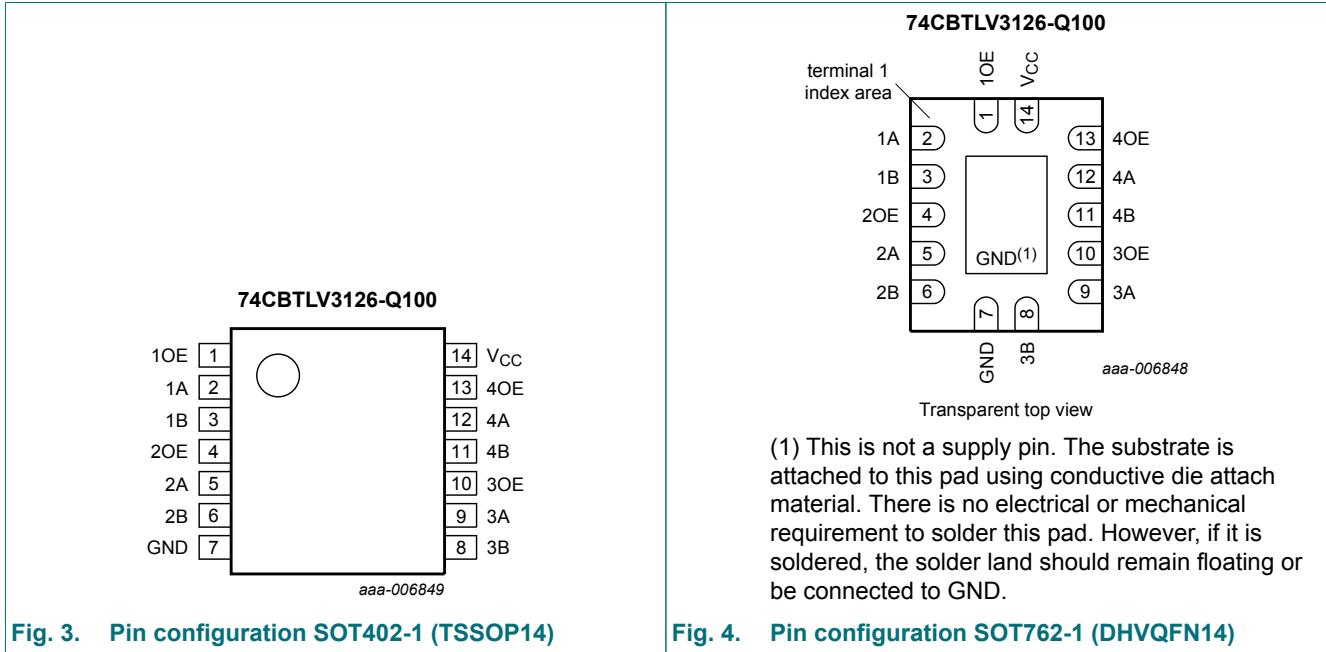
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Fig. 1. Logic symbol

Fig. 2. Logic diagram (one switch)

## 5. Pinning information

### 5.1. Pinning



### 5.2. Pin description

Table 2. Pin description

| Symbol             | Pin          | Description         |
|--------------------|--------------|---------------------|
| 1OE, 2OE, 3OE, 4OE | 1, 4, 10, 13 | output enable input |
| 1A, 2A, 3A, 4A     | 2, 5, 9, 12  | A input/output      |
| 1B, 2B, 3B, 4B     | 3, 6, 8, 11  | B output/input      |
| GND                | 7            | ground (0 V)        |
| V <sub>CC</sub>    | 14           | supply voltage      |

## 6. Functional description

Table 3. Function table

H = HIGH voltage level; L = LOW voltage level.

| Output enable input nOE | Function switch |
|-------------------------|-----------------|
| L                       | OFF-state       |
| H                       | ON-state        |

## 7. Limiting values

**Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol    | Parameter               | Conditions                        | Min  | Max            | Unit |
|-----------|-------------------------|-----------------------------------|------|----------------|------|
| $V_{CC}$  | supply voltage          |                                   | -0.5 | +4.6           | V    |
| $V_I$     | input voltage           | control inputs [1]                | -0.5 | +4.6           | V    |
| $V_{SW}$  | switch voltage          | enable and disable mode [2]       | -0.5 | $V_{CC} + 0.5$ | V    |
| $I_{IK}$  | input clamping current  | $V_I < -0.5$ V                    | -50  | -              | mA   |
| $I_{SK}$  | switch clamping current | $V_I < -0.5$ V                    | -50  | -              | mA   |
| $I_{SW}$  | switch current          | $V_{SW} = 0$ V to $V_{CC}$        | -    | $\pm 128$      | mA   |
| $I_{CC}$  | supply current          |                                   | -    | +100           | mA   |
| $I_{GND}$ | ground current          |                                   | -100 | -              | mA   |
| $T_{stg}$ | storage temperature     |                                   | -65  | +150           | °C   |
| $P_{tot}$ | total power dissipation | $T_{amb} = -40$ °C to +125 °C [3] | -    | 500            | mW   |

[1] The minimum input voltage rating may be exceeded if the input clamping current ratings are observed.

[2] The switch voltage ratings may be exceeded if switch clamping current ratings are observed

[3] For TSSOP14 packages:  $P_{tot}$  derates linearly with 5.5 mW/K above 60 °C.

For DHVQFN14 packages:  $P_{tot}$  derates linearly with 4.5 mW/K above 60 °C.

## 8. Recommended operating conditions

**Table 5. Recommended operating conditions**

| Symbol              | Parameter                           | Conditions                         | Min | Max      | Unit |
|---------------------|-------------------------------------|------------------------------------|-----|----------|------|
| $V_{CC}$            | supply voltage                      |                                    | 2.3 | 3.6      | V    |
| $V_I$               | input voltage                       | control inputs                     | 0   | 3.6      | V    |
| $V_{SW}$            | switch voltage                      | enable and disable mode            | 0   | $V_{CC}$ | V    |
| $T_{amb}$           | ambient temperature                 |                                    | -40 | +125     | °C   |
| $\Delta t/\Delta V$ | input transition rise and fall rate | pin nOE; $V_{CC} = 2.3$ V to 3.6 V | 0   | 200      | ns/V |

## 9. Static characteristics

**Table 6. Static characteristics**

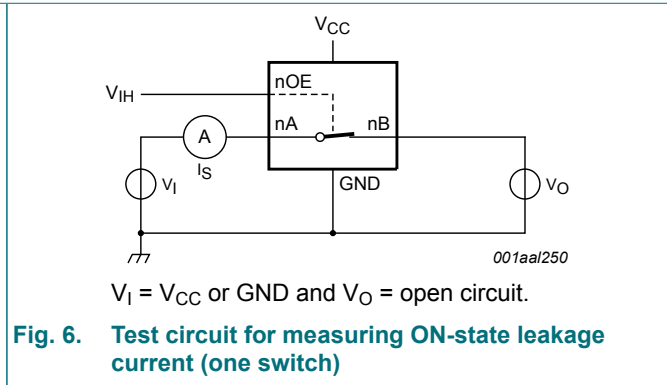
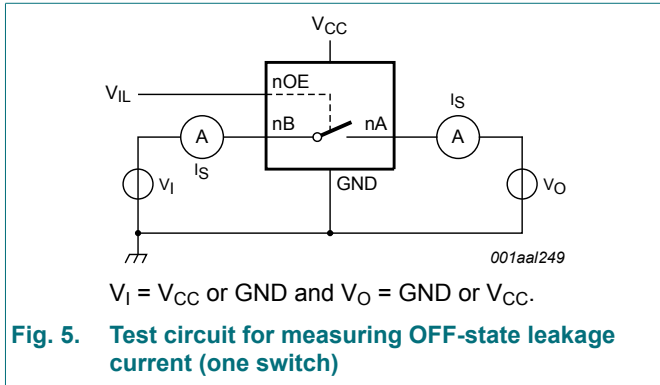
At recommended operating conditions voltages are referenced to GND (ground = 0 V).

| Symbol              | Parameter                 | Conditions   | T <sub>amb</sub> = -40 °C to +85 °C |         |      | T <sub>amb</sub> = -40 °C to +125 °C |      | Unit |
|---------------------|---------------------------|--|-------------------------------------|---------|------|--------------------------------------|------|------|
|                     |                           |  | Min                                 | Typ [1] | Max  | Min                                  | Max  |      |
| V <sub>IH</sub>     | HIGH-level input voltage  | V <sub>CC</sub> = 2.3 V to 2.7 V   | 1.7                                 | -       | -    | 1.7                                  | -    | V    |
|                     |                           | V <sub>CC</sub> = 3.0 V to 3.6 V   | 2.0                                 | -       | -    | 2.0                                  | -    | V    |
| V <sub>IL</sub>     | LOW-level input voltage   | V <sub>CC</sub> = 2.3 V to 2.7 V   | -                                   | -       | 0.7  | -                                    | 0.7  | V    |
|                     |                           | V <sub>CC</sub> = 3.0 V to 3.6 V   | -                                   | -       | 0.9  | -                                    | 0.9  | V    |
| I <sub>I</sub>      | input leakage current     | pin nOE; V <sub>I</sub> = GND to V <sub>CC</sub> ;<br>V <sub>CC</sub> = 3.6 V  | -                                   | -       | ±1.0 | -                                    | ±20  | µA   |
| I <sub>S(OFF)</sub> | OFF-state leakage current | V <sub>CC</sub> = 3.6 V; see Fig. 5  | -                                   | -       | ±1   | -                                    | ±20  | µA   |
| I <sub>S(ON)</sub>  | ON-state leakage current  | V <sub>CC</sub> = 3.6 V; see Fig. 6  | -                                   | -       | ±1   | -                                    | ±20  | µA   |
| I <sub>OFF</sub>    | power-off leakage current | V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V;<br>V <sub>CC</sub> = 0 V  | -                                   | -       | ±10  | -                                    | ±50  | µA   |
| I <sub>CC</sub>     | supply current            | V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A;<br>V <sub>SW</sub> = GND or V <sub>CC</sub> ;<br>V <sub>CC</sub> = 3.6 V | -                                   | -       | 10   | -                                    | 50   | µA   |
| ΔI <sub>CC</sub>    | additional supply current | pin nOE; V <sub>I</sub> = V <sub>CC</sub> - 0.6 V; [2]<br>V <sub>SW</sub> = GND or V <sub>CC</sub> ;<br>V <sub>CC</sub> = 3.6 V          | -                                   | -       | 300  | -                                    | 2000 | µA   |
| C <sub>I</sub>      | input capacitance         | pin nOE; V <sub>CC</sub> = 3.3 V;<br>V <sub>I</sub> = 0 V to 3.3 V   | -                                   | 0.9     | -    | -                                    | -    | pF   |
| C <sub>S(OFF)</sub> | OFF-state capacitance     | V <sub>CC</sub> = 3.3 V; V <sub>I</sub> = 0 V to 3.3 V   | -                                   | 5.2     | -    | -                                    | -    | pF   |
| C <sub>S(ON)</sub>  | ON-state capacitance      | V <sub>CC</sub> = 3.3 V; V <sub>I</sub> = 0 V to 3.3 V   | -                                   | 14.3    | -    | -                                    | -    | pF   |

[1] All typical values are measured at T<sub>amb</sub> = 25 °C.

[2] One input at 3 V, other inputs at V<sub>CC</sub> or GND.

9.1. Test circuits



9.2. ON resistance

Table 7. Resistance  $R_{ON}$

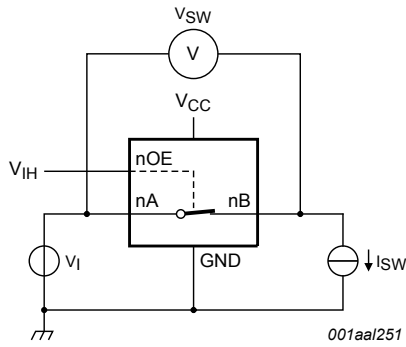
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 7.

| Symbol                                      | Parameter     | Conditions  | $T_{amb} = -40\text{ }^{\circ}\text{C to }+85\text{ }^{\circ}\text{C}$ |         |      | $T_{amb} = -40\text{ }^{\circ}\text{C to }+125\text{ }^{\circ}\text{C}$ |      | Unit     |
|---|---------------|---|--|---------|------|---|------|----------|
|   |               |   | Min  | Typ [1] | Max  | Min   | Max  |          |
| $R_{ON}$                                    | ON resistance | $V_{CC} = 2.3\text{ V to }2.7\text{ V};$<br>see Fig. 8 to Fig. 10 [2] |  |         |      |   |      |          |
|   |               | $I_{SW} = 64\text{ mA}; V_I = 0\text{ V}$                             | -  | 4.2     | 8.0  | -   | 15.0 | $\Omega$ |
|   |               | $I_{SW} = 24\text{ mA}; V_I = 0\text{ V}$                             | -  | 4.2     | 8.0  | -   | 15.0 | $\Omega$ |
|   |               | $I_{SW} = 15\text{ mA}; V_I = 1.7\text{ V}$                           | -  | 8.4     | 40.0 | -   | 60.0 | $\Omega$ |
|   |               | $V_{CC} = 3.0\text{ V to }3.6\text{ V};$<br>see Fig. 11 to Fig. 13    |  |         |      |   |      |          |
|   |               | $I_{SW} = 64\text{ mA}; V_I = 0\text{ V}$                             | -  | 4.0     | 7.0  | -   | 11.0 | $\Omega$ |
|   |               | $I_{SW} = 24\text{ mA}; V_I = 0\text{ V}$                             | -  | 4.0     | 7.0  | -   | 11.0 | $\Omega$ |
| $I_{SW} = 15\text{ mA}; V_I = 2.4\text{ V}$ | -             | 6.2   | 15.0   | -       | 25.5 | $\Omega$  |      |          |

[1] Typical values are measured at  $T_{amb} = 25\text{ }^{\circ}\text{C}$  and nominal  $V_{CC}$ .

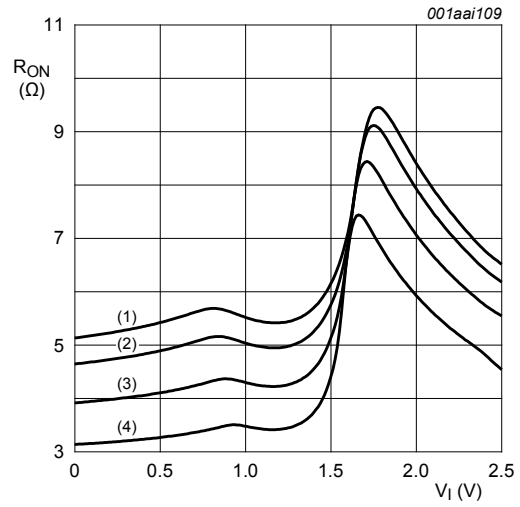
[2] Measured by the voltage drop between the A and B terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

9.3. ON resistance test circuit and graphs



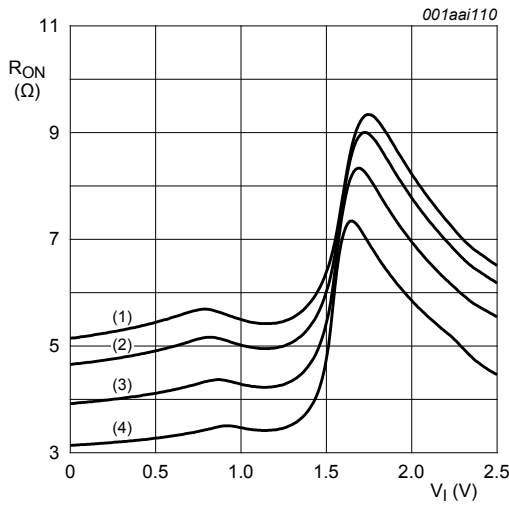
$R_{ON} = V_{SW} / I_{SW}$ .

Fig. 7. Test circuit for measuring ON resistance (one switch)



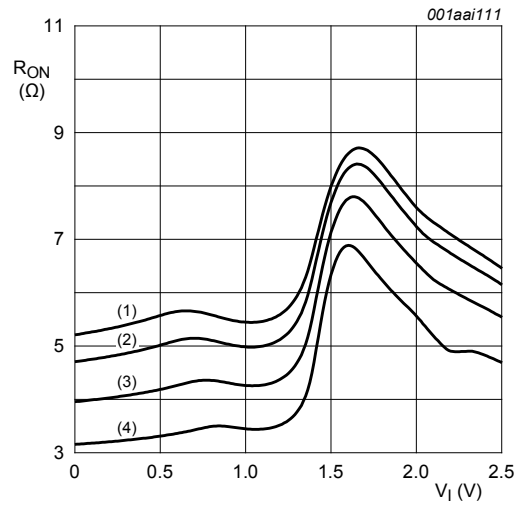
- (1)  $T_{amb} = 125\text{ }^{\circ}\text{C}$ .
- (2)  $T_{amb} = 85\text{ }^{\circ}\text{C}$ .
- (3)  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .
- (4)  $T_{amb} = -40\text{ }^{\circ}\text{C}$ .

Fig. 8. ON resistance as a function of input voltage;  $V_{CC} = 2.5\text{ V}$ ;  $I_{SW} = 15\text{ mA}$



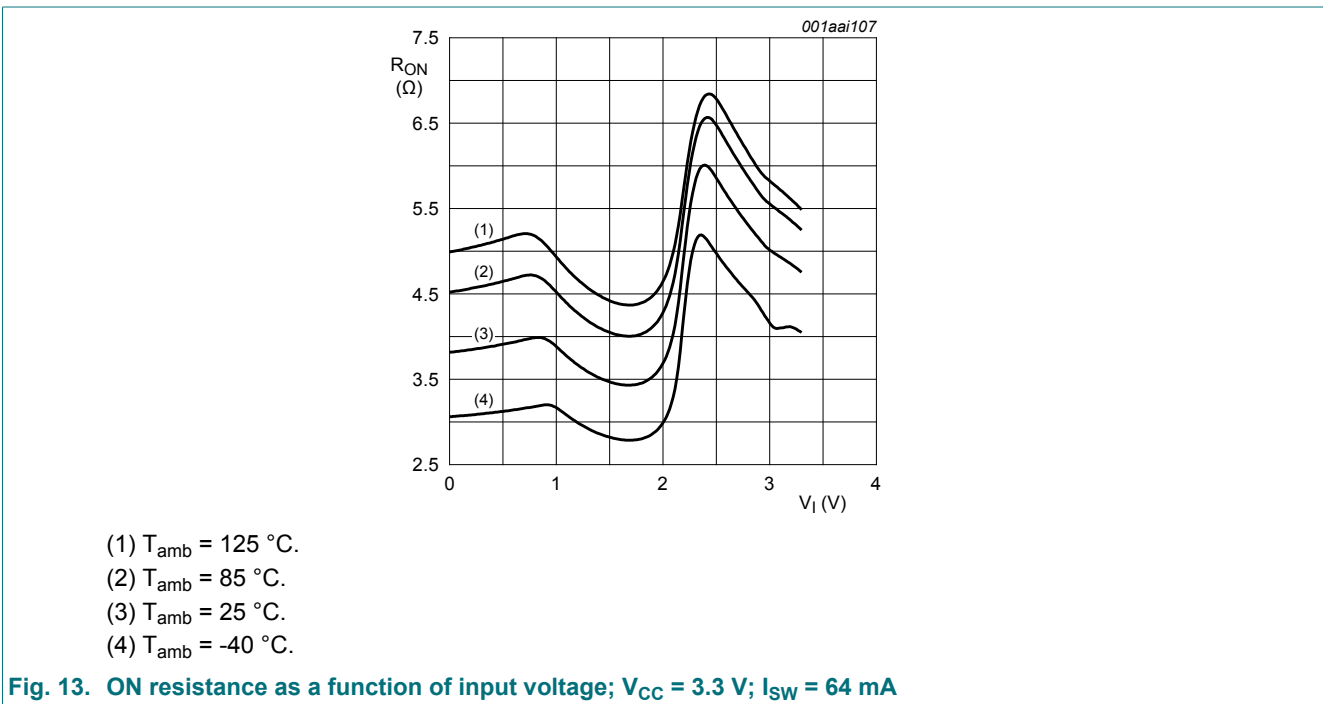
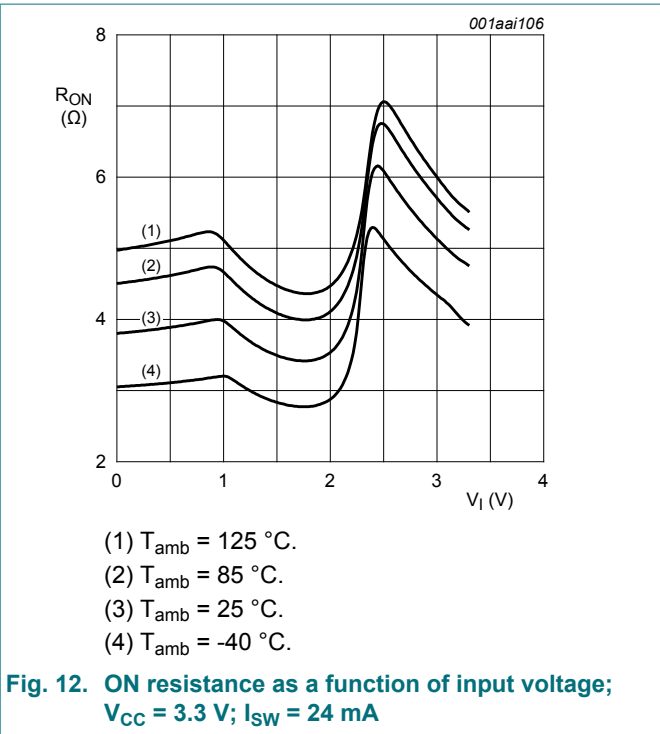
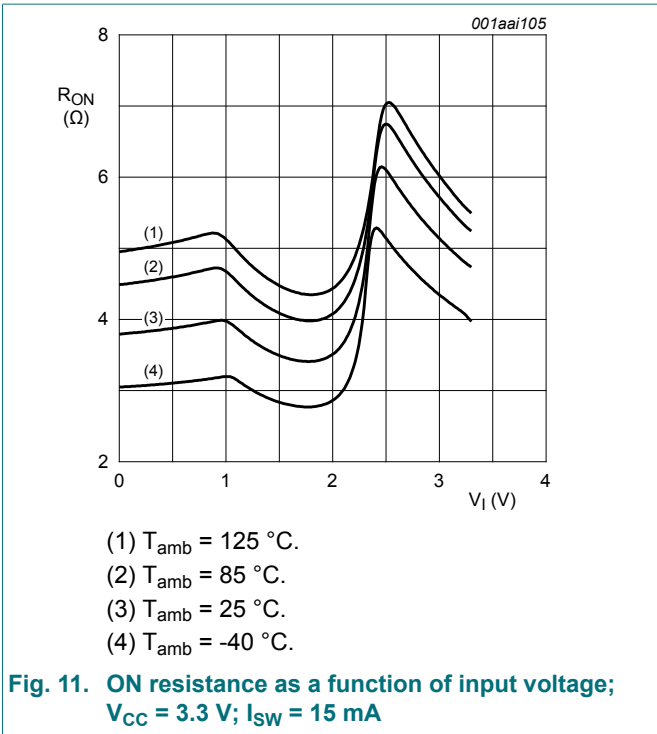
- (1)  $T_{amb} = 125\text{ }^{\circ}\text{C}$ .
- (2)  $T_{amb} = 85\text{ }^{\circ}\text{C}$ .
- (3)  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .
- (4)  $T_{amb} = -40\text{ }^{\circ}\text{C}$ .

Fig. 9. ON resistance as a function of input voltage;  $V_{CC} = 2.5\text{ V}$ ;  $I_{SW} = 24\text{ mA}$



- (1)  $T_{amb} = 125\text{ }^{\circ}\text{C}$ .
- (2)  $T_{amb} = 85\text{ }^{\circ}\text{C}$ .
- (3)  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .
- (4)  $T_{amb} = -40\text{ }^{\circ}\text{C}$ .

Fig. 10. ON resistance as a function of input voltage;  $V_{CC} = 2.5\text{ V}$ ;  $I_{SW} = 64\text{ mA}$





## 10. Dynamic characteristics

**Table 8. Dynamic characteristics**

$GND = 0\text{ V}$ ; for test circuit see Fig. 17

| Symbol    | Parameter         | Conditions                               | $T_{amb} = -40\text{ °C to }+85\text{ °C}$ |         |      | $T_{amb} = -40\text{ °C to }+125\text{ °C}$ |      | Unit |
|-----------|-------------------|--|--|---------|------|---|------|------|
|           |                   |  | Min  | Typ [1] | Max  | Min   | Max  |      |
| $t_{pd}$  | propagation delay | nA to nB or nB to nA; see Fig. 15 [2][3] |  |         |      |   |      |      |
|           |                   | $V_{CC} = 2.3\text{ V to }2.7\text{ V}$  | -  | -       | 0.13 | -   | 0.20 | ns   |
|           |                   | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$  | -  | -       | 0.20 | -   | 0.31 | ns   |
| $t_{en}$  | enable time       | nOE to nA or nB; see Fig. 16 [4]         |  |         |      |   |      |      |
|           |                   | $V_{CC} = 2.3\text{ V to }2.7\text{ V}$  | 1.0  | 2.5     | 4.5  | 1.0   | 6.0  | ns   |
|           |                   | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$  | 1.0  | 2.2     | 4.2  | 1.0   | 6.0  | ns   |
| $t_{dis}$ | disable time      | nOE to nA or nB; see Fig. 16 [5]         |  |         |      |   |      |      |
|           |                   | $V_{CC} = 2.3\text{ V to }2.7\text{ V}$  | 1.0  | 2.6     | 4.7  | 1.0   | 6.5  | ns   |
|           |                   | $V_{CC} = 3.0\text{ V to }3.6\text{ V}$  | 1.0  | 3.4     | 4.8  | 1.0   | 6.5  | ns   |

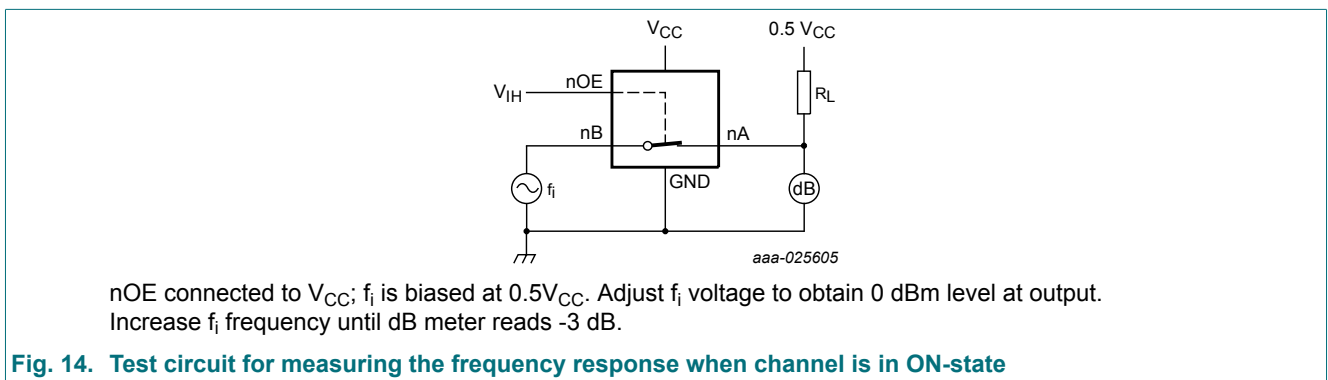
- [1] All typical values are measured at  $T_{amb} = 25\text{ °C}$  and at nominal  $V_{CC}$ .
- [2] The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the load capacitance, when driven by an ideal voltage source (zero output impedance).
- [3]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .
- [4]  $t_{en}$  is the same as  $t_{PZH}$  and  $t_{PZL}$ .
- [5]  $t_{dis}$  is the same as  $t_{PHZ}$  and  $t_{PLZ}$ .

### 10.1. Additional dynamic characteristics

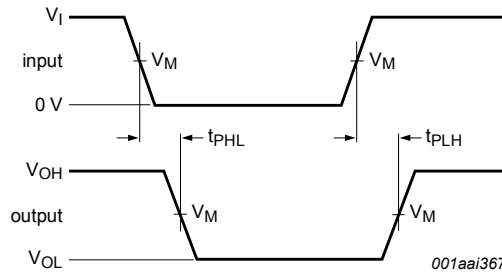
**Table 9. Additional dynamic characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V);

| Symbol       | Parameter                | Conditions  | $T_{amb} = 25\text{ °C}$ |     |     | Unit |
|--------------|--------------------------|---|--------------------------|-----|-----|------|
|              |                          |   | Min                      | Typ | Max |      |
| $f_{(-3dB)}$ | -3 dB frequency response | $V_I = GND\text{ or }V_{CC}$ ; $t_r = t_f \leq 2.5\text{ ns}$ ;<br>$V_{CC} = 3.3\text{ V}$ ; $R_L = 50\ \Omega$ ; see Fig. 14 | -                        | 406 | -   | MHz  |



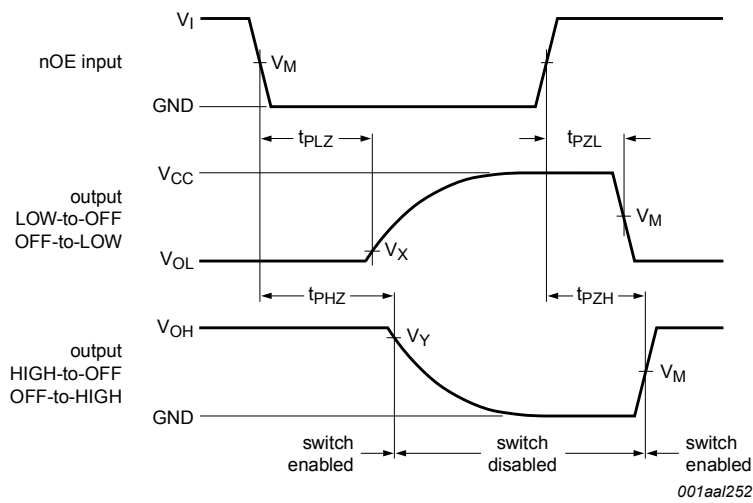
10.2. Waveforms and test circuit



Measurement points are given in [Table 10](#).

Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

Fig. 15. The data input (nA or nB) to output (nB or nA) propagation delays



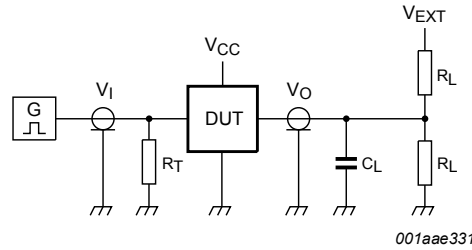
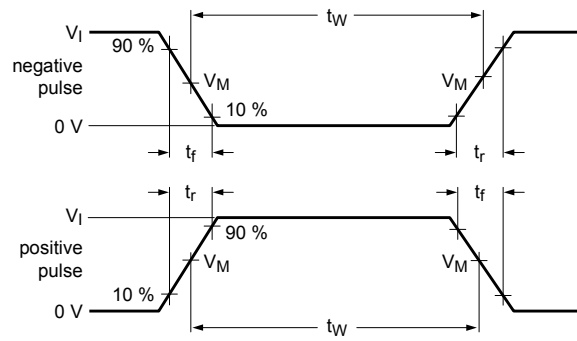
Measurement points are given in [Table 10](#).

Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

Fig. 16. Enable and disable times

Table 10. Measurement points

| Supply voltage | Input       |          | Output      |                   |                   |
|----------------|-------------|----------|-------------|-------------------|-------------------|
| $V_{CC}$       | $V_M$       | $V_I$    | $V_M$       | $V_X$             | $V_Y$             |
| 2.3 V to 2.7 V | $0.5V_{CC}$ | $V_{CC}$ | $0.5V_{CC}$ | $V_{OL} + 0.15 V$ | $V_{OH} - 0.15 V$ |
| 3.0 V to 3.6 V | $0.5V_{CC}$ | $V_{CC}$ | $0.5V_{CC}$ | $V_{OL} + 0.3 V$  | $V_{OH} - 0.3 V$  |



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Test data is given in [Table 11](#).

Definitions for test circuit:

$R_L$  = Load resistance.

$C_L$  = Load capacitance including jig and probe capacitance.

$R_T$  = Termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator.

$V_{EXT}$  = External voltage for measuring switching times.

**Fig. 17. Test circuit for measuring switching times**

**Table 11. Test data**

| Supply voltage | Load  |              |               | $V_{EXT}$          |                    |                    |
|----------------|-------|--------------|---------------|--------------------|--------------------|--------------------|
| $V_{CC}$       | $C_L$ | $R_L$        | $t_r = t_f$   | $t_{PLH}, t_{PHL}$ | $t_{PZH}, t_{PHZ}$ | $t_{PZL}, t_{PLZ}$ |
| 2.3 V to 2.7 V | 30 pF | 500 $\Omega$ | $\leq 2.0$ ns | open               | GND                | $2V_{CC}$          |
| 3.0 V to 3.6 V | 50 pF | 500 $\Omega$ | $\leq 2.0$ ns | open               | GND                | $2V_{CC}$          |

### 11. Package outline

TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1

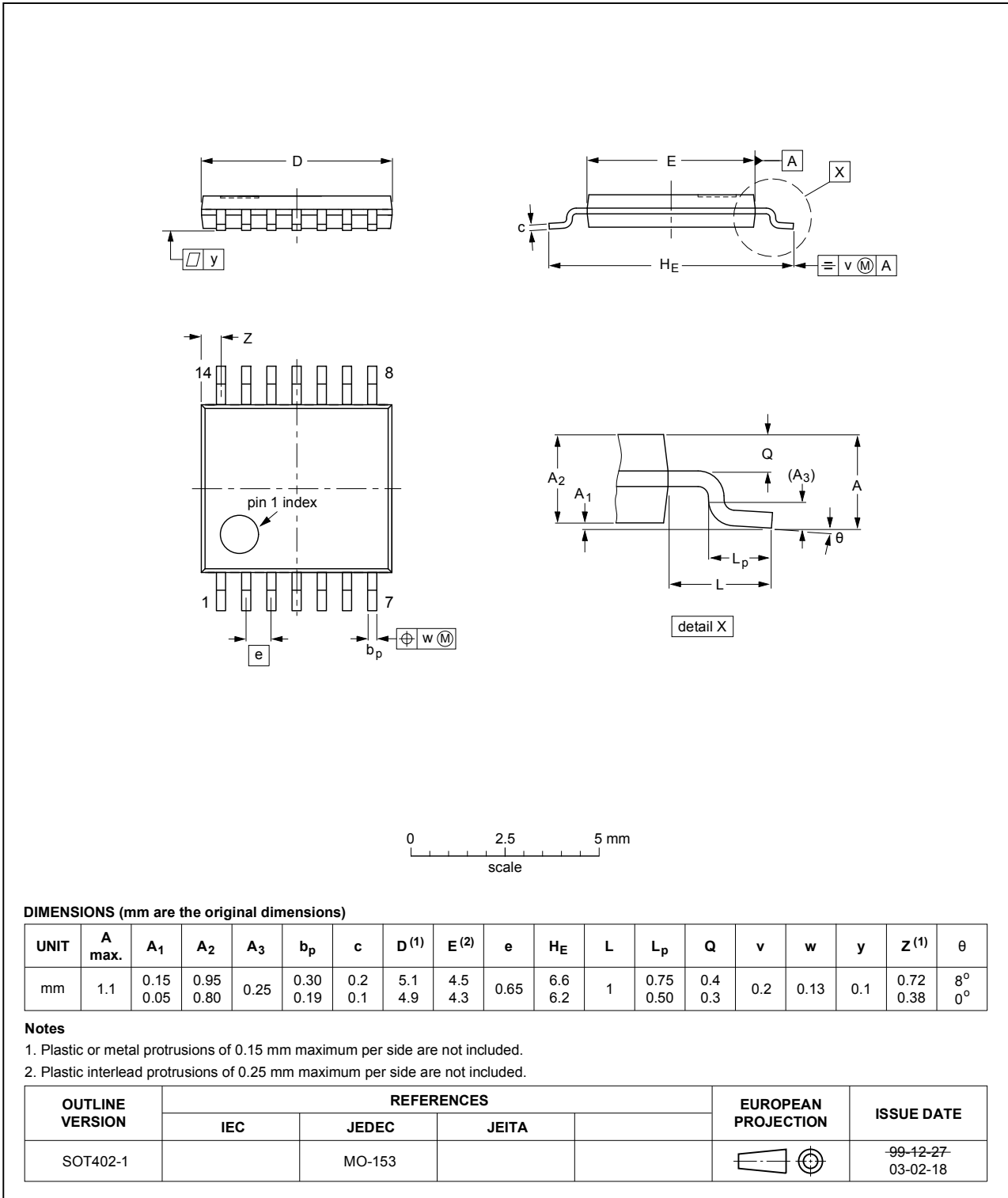


Fig. 18. Package outline SOT402-1 (TSSOP14)

DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 x 3 x 0.85 mm

SOT762-1

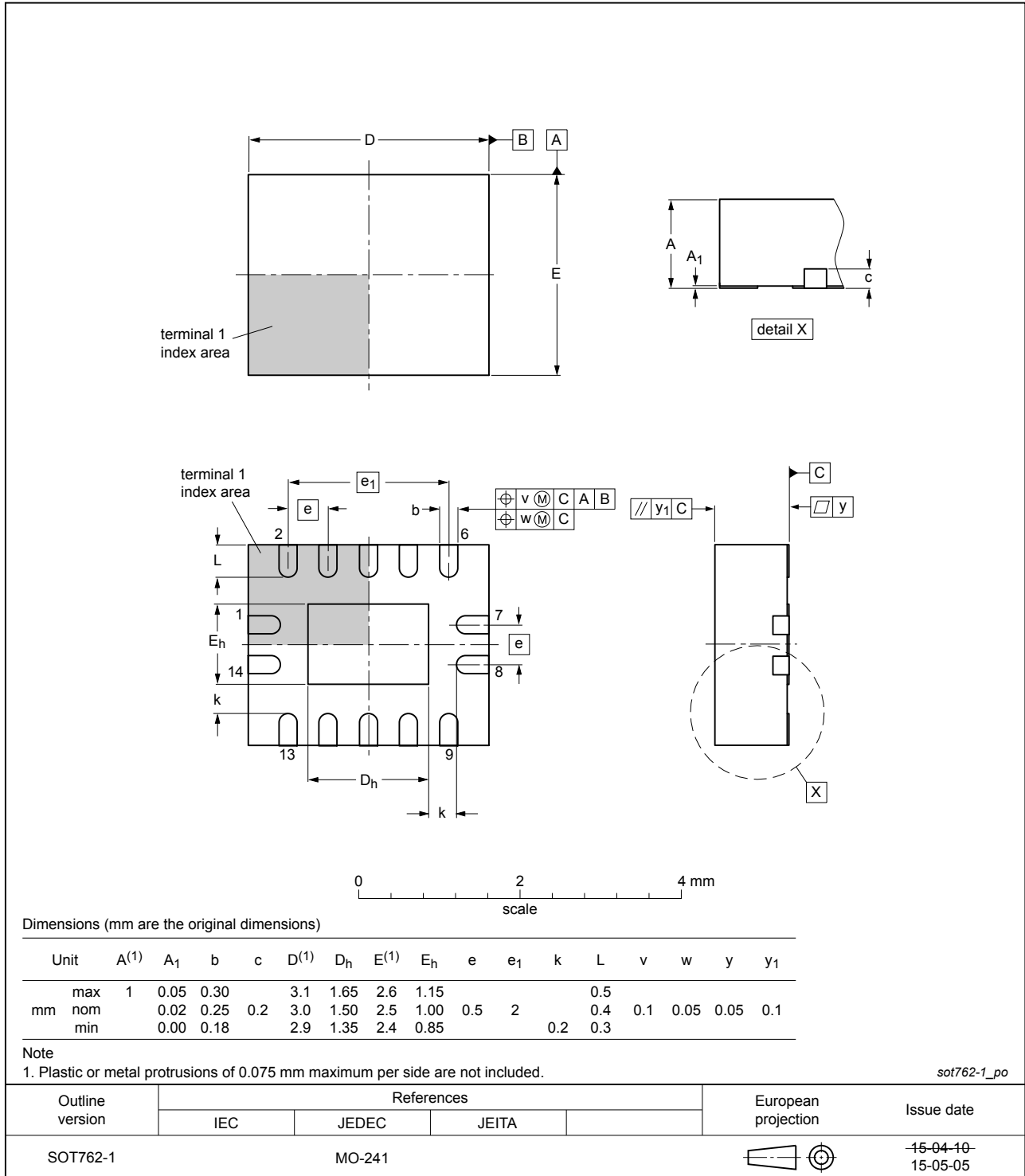


Fig. 19. Package outline SOT762-1 (DHVQFN14)

## 12. Abbreviations

Table 12. Abbreviations

| Acronym | Description                             |
|---------|---|
| CMOS    | Complementary Metal-Oxide Semiconductor |
| DUT     | Device Under Test                       |
| ESD     | ElectroStatic Discharge                 |
| HBM     | Human Body Model                        |
| MIL     | Military                                |
| MM      | Machine Model                           |

## 13. Revision history

Table 13. Revision history

| Document ID          | Release date  | Data sheet status  | Change notice | Supersedes           |
|----------------------|---|--------------------|---------------|----------------------|
| 74CBTLV3126_Q100 v.3 | 20181009  | Product data sheet | -             | 74CBTLV3126_Q100 v.2 |
| Modifications:       | <ul style="list-style-type: none"> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul> |                    |               |                      |
| 74CBTLV3126_Q100 v.2 | 20161109  | Product data sheet | -             | 74CBTLV3126_Q100 v.1 |
| Modifications:       | <ul style="list-style-type: none"> <li><a href="#">Section 10.1</a> added.</li> </ul>   |                    |               |                      |
| 74CBTLV3126_Q100 v.1 | 20130403  | Product data sheet | -             | -                    |

## 14. Legal information

### Data sheet status

| Document status [1][2]         | Product status [3] | Definition  |
|--------------------------------|--------------------|---|
| Objective [short] data sheet   | Development        | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification      | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production         | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <https://www.nexperia.com>.

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